

General Description

The ICS840272I is a PLL-based Frequency Translator intended for use in Synchronous Ethernet applications. This high performance device is optimized to generate 25MHz and 8kHz LVCMOS clock outputs. The ICS840272I accepts the following differential or single-ended input signals: 161.1328125MHz (10GbE Mode), 156.25MHz (1GbE Mode), or 125MHz (Recovered clock from 10/100/1000BaseT Ethernet PHY). The extended temperature range supports telecommunication and networking end equipment requirements.

Pin Assignment

VDD	1	16	VDDO
LOCK_DT	2	15	QA
REF_SEL	3	14	QB
SEL0	4	13	GND
SEL1	5	12	CLK0
OE	6	11	nCLK0
VDDA	7	10	CLK1
GND	8	9	nCLK1

ICS840272I

16 Lead TSSOP

4.40mm x 5.0mm x 0.925mm package body

G Package

Top View

Features

- Two single-ended outputs (LVCMOS or LVTTTL levels), output impedance: 17Ω
- Single-ended lock detect output (LVCMOS or LVTTTL levels)
- Two selectable differential clock inputs
- Differential input pair (CLKx, nCLKx) accepts LVPECL, LVDS, LVHSTL, SSTL, HCSL input levels
- Internal resistor bias on nCLK pin allows the user to drive CLK input with external single-ended (LVCMOS/ LVTTTL) input levels
- Selectable input frequencies: 161.1328MHz, 156.25MHz or 125MHz
- Output frequency: 25MHz, 8kHz
- Full 3.3V supply voltage
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) package

Block Diagram

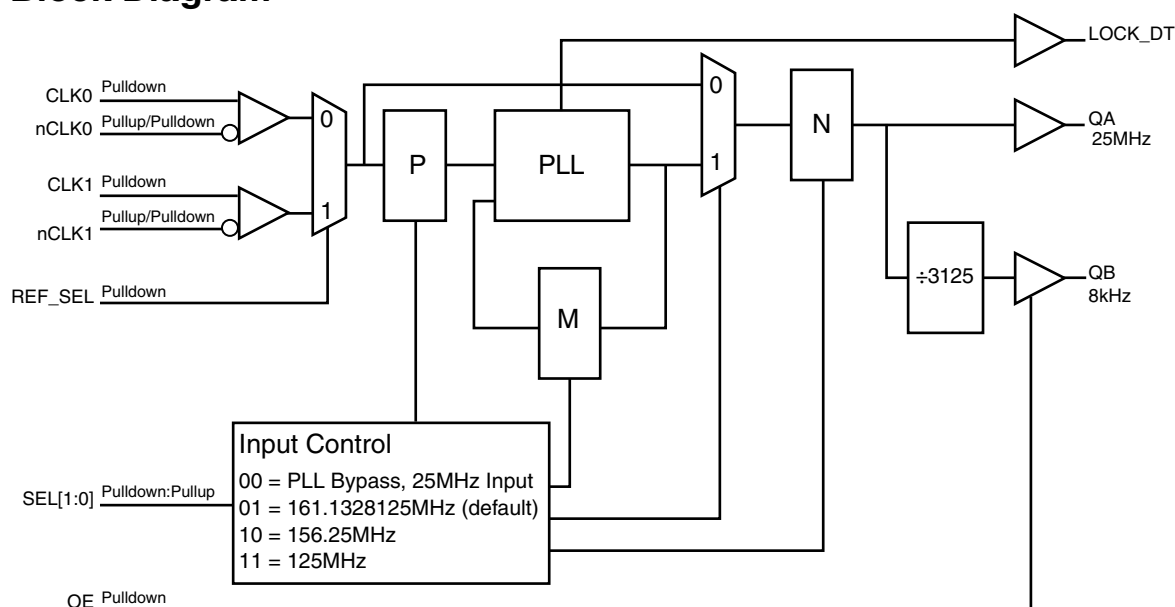


Table 1. Pin Descriptions

Number	Name	Type		Description
1	V _{DD}	Power		Core supply pin.
2	LOCK_DT	Output		Lock detect. Logic HIGH when PLL is locked.
3	REF_SEL	Input	Pulldown	Selects the input reference clock. When LOW, selects CLK0, nCLK0. When HIGH, selects CLK1, nCLK1. LVCMOS/LVTTL interface levels.
4	SEL0	Input	Pullup	Selects the input reference frequency and the PLL bypass mode. See Table 3A. LVCMOS/LVTTL interface levels.
5	SEL1	Input	Pulldown	Selects the input reference frequency and the PLL bypass mode. See Table 3A. LVCMOS/LVTTL interface levels.
6	OE	Input	Pulldown	8kHz output enable pin. When LOW, QB is disabled. When HIGH, QB is enabled. LVCMOS/LVTTL interface levels. See Table 3B.
7	V _{DDA}	Power		Analog supply pin.
8, 13	GND	Power		Power supply ground.
9	nCLK1	Input	Pullup/ Pulldown	Inverting differential clock input. Internal resistor bias to V _{DD} /2.
10	CLK1	Input	Pulldown	Non-inverting differential clock input.
11	nCLK0	Input	Pullup/ Pulldown	Inverting differential clock input. Internal resistor bias to V _{DD} /2.
12	CLK0	Input	Pulldown	Non-inverting differential clock input.
14	QB	Output		Single-ended clock output. LVCMOS/LVTTL interface levels.
15	QA	Output		Single-ended clock output. LVCMOS/LVTTL interface levels.
16	V _{DDO}	Power		Output supply pin.

NOTE: *Pullup* and *Pulldown* refer to internal input resistors. See Table 2, *Pin Characteristics*, for typical values.

Table 2. Pin Characteristics

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C _{IN}	Input Capacitance			4		pF
R _{PULLUP}	Input Pullup Resistor			51		kΩ
R _{PULLDOWN}	Input Pulldown Resistor			51		kΩ
R _{OUT}	Output Impedance	V _{DDO} = 3.465V		17		Ω

Function Tables

Table 3A. SEL[1:0] Function Table

Inputs			Function	Output (MHz)
SEL1	SEL0	CLKx, nCLKx (MHz)	Mode	QA
0	0	25	PLL Bypass	25
0 (default)	1 (default)	161.1328125	PLL Enabled	25
1	0	156.25	PLL Enabled	25
1	1	125	PLL Enabled	25

Table 3B. OE Function Table

Control Input	Function
OE	QB Output
0 (default)	Disabled (High impedance)
1	Enabled

Absolute Maximum Ratings

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V_{DD}	4.6V
Inputs, V_I	-0.5V to $V_{DD} + 0.5V$
Outputs, I_O (LVCMOS)	-0.5V to $V_{DDO} + 0.5V$
Package Thermal Impedance, θ_{JA}	81.2°C/W (0 mps)
Storage Temperature, T_{STG}	-65°C to 150°C

DC Electrical Characteristics

Table 4A. Power Supply DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{DD}	Core Supply Voltage		3.135	3.3	3.465	V
V_{DDA}	Analog Supply Voltage		$V_{DD} - 0.11$	3.3	V_{DD}	V
V_{DDO}	Output Supply Voltage		3.135	3.3	3.465	V
I_{DD}	Power Supply Current				57	mA
I_{DDA}	Analog Supply Current				11	mA
I_{DDO}	Output Supply Current				5	mA

Table 4B. LVCMOS/LVTTL DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V_{IH}	Input High Voltage	$V_{DD} = 3.465V$	2		$V_{DD} + 0.3$	V
V_{IL}	Input Low Voltage	$V_{DD} = 3.465V$	-0.3		0.8	V
I_{IH}	Input High Current	OE, SEL1, REF_SEL $V_{DD} = V_{IN} = 3.465V$			150	μA
		SEL0 $V_{DD} = V_{IN} = 3.465V$			5	μA
I_{IL}	Input Low Current	OE, SEL1, REF_SEL $V_{DD} = 3.465V, V_{IN} = 0V$	-5			μA
		SEL0 $V_{DD} = 3.465V, V_{IN} = 0V$	-150			μA
V_{OH}	Output High Voltage	$I_{OH} = -12mA$	2.6			V
V_{OL}	Output Low Voltage	$I_{OL} = 12mA$			0.5	V

Table 4C. Differential DC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
I_{IH}	Input High Current	CLK[0:1], nCLK[0:1]	$V_{DD} = V_{IN} = 3.465V$			150	μA
I_{IL}	Input Low Current	CLK[0:1]	$V_{DD} = 3.465V$, $V_{IN} = 0V$	-5			μA
		nCLK[0:1]	$V_{DD} = 3.465V$, $V_{IN} = 0V$	-150			μA
V_{PP}	Peak-to-Peak Voltage; NOTE 1			0.15		1.3	V
V_{CMR}	Common Mode Input Voltage; NOTE 1, 2			GND + 0.5		$V_{DD} - 0.85$	V

NOTE 1: V_{IL} should not be less than -0.3V.NOTE 2: Common mode input voltage is defined as V_{IH} .

AC Electrical Characteristics

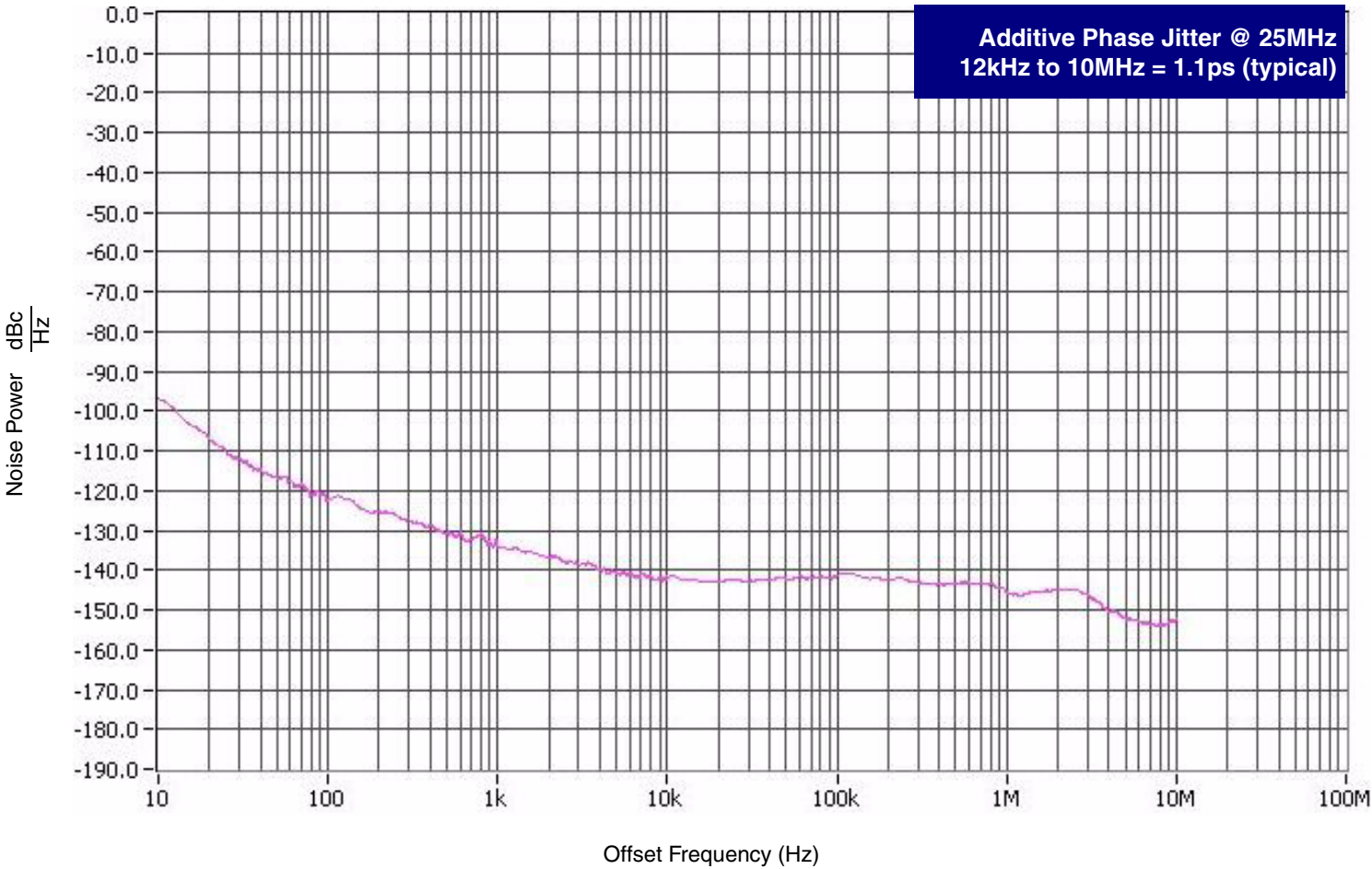
Table 5. AC Characteristics, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, $T_A = -40^\circ\text{C}$ to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
f_{OUT}	Output Frequency	QA			25		MHz
		QB			8		kHz
$f_{jit}(\emptyset)$	RMS Phase Jitter (Random); NOTE 1	QA	25MHz, Integration Range: 12kHz – 10MHz		1.1		ps
$f_{jit}(cc)$	Cycle-to-Cycle Jitter	QA	25MHz			37	ps
t_R / t_F	Output Rise/Fall Time	QA	20% to 80%	450		1100	ps
		QB	20% to 80%	450		1100	ps
odc	Output Duty Cycle	QA		47		53	%
		QB		47		53	%

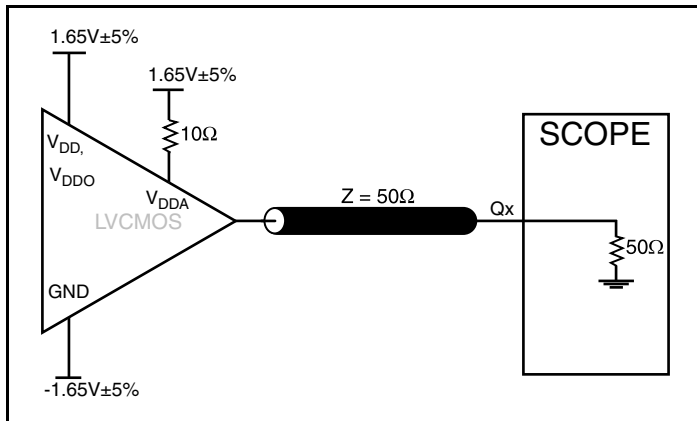
NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when the device is mounted in a test socket with maintained transverse airflow greater than 500 lfm. The device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Refer to Phase Noise plot.

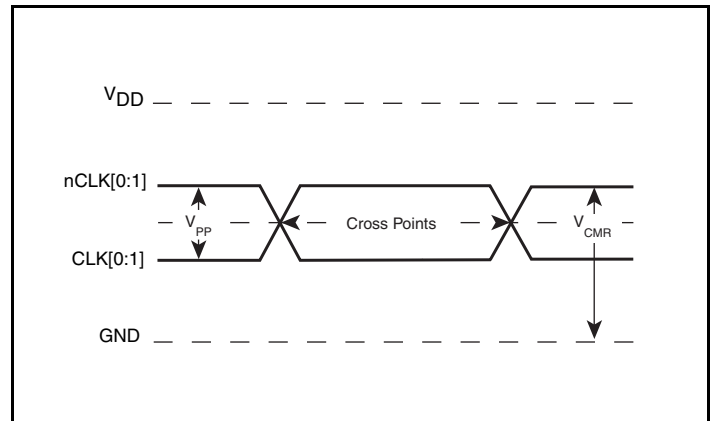
Typical Phase Noise at 25MHz



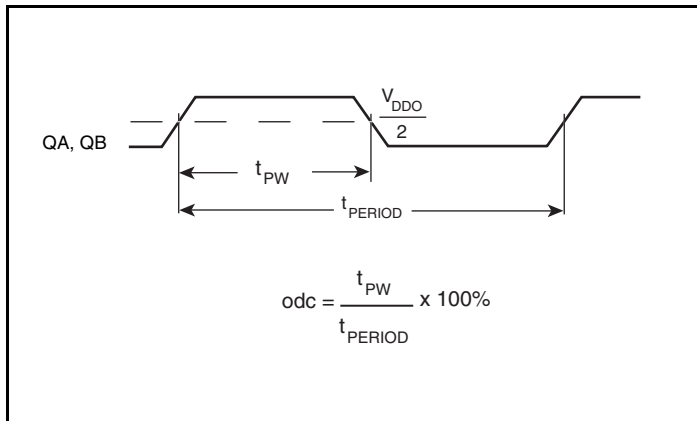
Parameter Measurement Information



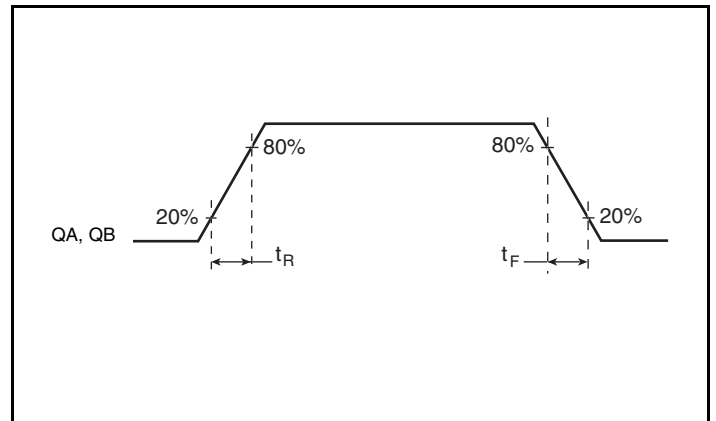
LVC MOS Output Load AC Test Circuit



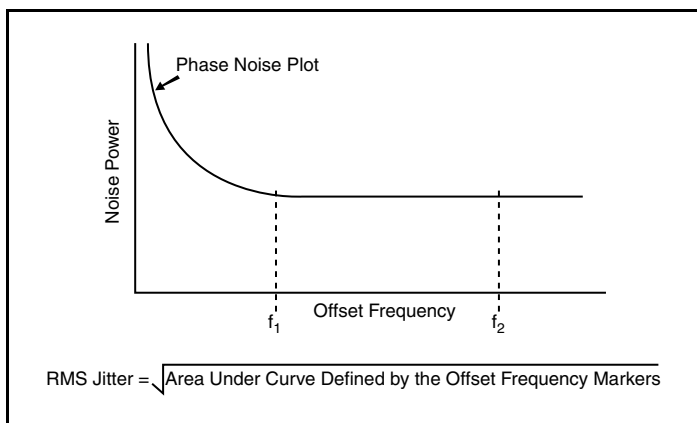
Differential Input Level



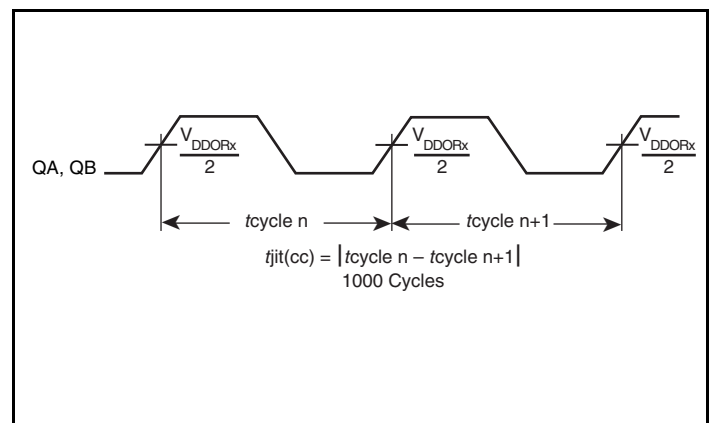
Output Duty Cycle/Pulse Width/Period



Output Rise/Fall Time



RMS Phase Jitter



Cycle-to-Cycle Jitter

Applications Information

Power Supply Filtering Technique

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The ICS840272I provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{DD} , V_{DDA} and V_{DDO} should be individually connected to the power supply plane through vias, and $0.01\mu\text{F}$ bypass capacitors should be used for each pin. *Figure 1* illustrates this for a generic V_{DD} pin and also shows that V_{DDA} requires that an additional 10Ω resistor along with a $10\mu\text{F}$ bypass capacitor be connected to the V_{DDA} pin.

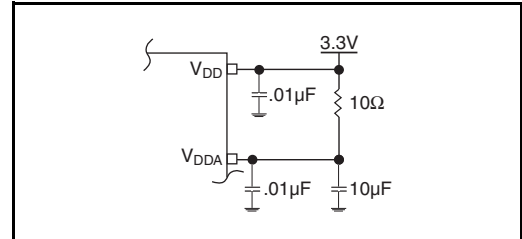


Figure 1. Power Supply Filtering

Recommendations for Unused Input and Output Pins

Inputs:

LVC MOS Control Pins

All control pins have internal pullups or pulldowns; additional resistance is not required but can be added for additional protection. A $1\text{k}\Omega$ resistor can be used.

CLK/nCLK Inputs

For applications not requiring the use of the differential input, both CLK and nCLK can be left floating. Though not required, but for additional protection, a $1\text{k}\Omega$ resistor can be tied from CLK to ground.

Outputs:

LVC MOS Outputs

All unused LVC MOS output can be left floating. There should be no trace attached.

Wiring the Differential Input to Accept Single-Ended Levels

Figure 2 shows how a differential input can be wired to accept single ended levels. The reference voltage $V_{REF} = V_{DD}/2$ is generated by the bias resistors R1 and R2. The bypass capacitor (C1) is used to help filter noise on the DC bias. This bias circuit should be located as close to the input pin as possible. The ratio of R1 and R2 might need to be adjusted to position the V_{REF} in the center of the input voltage swing. For example, if the input clock swing is 2.5V and $V_{DD} = 3.3V$, R1 and R2 value should be adjusted to set V_{REF} at 1.25V. The values below are for when both the single ended swing and V_{DD} are at the same voltage. This configuration requires that the sum of the output impedance of the driver (R_o) and the series resistance (R_s) equals the transmission line impedance. In addition, matched termination at the input will attenuate the signal in half. This can be done in one of two ways. First, R3 and R4 in parallel should equal the transmission

line impedance. For most 50Ω applications, R3 and R4 can be 100Ω. The values of the resistors can be increased to reduce the loading for slower and weaker LVCMOS driver. When using single-ended signaling, the noise rejection benefits of differential signaling are reduced. Even though the differential input can handle full rail LVCMOS signaling, it is recommended that the amplitude be reduced. The datasheet specifies a lower differential amplitude, however this only applies to differential signals. For single-ended applications, the swing can be larger, however V_{IL} cannot be less than -0.3V and V_{IH} cannot be more than $V_{DD} + 0.3V$. Though some of the recommended components might not be used, the pads should be placed in the layout. They can be utilized for debugging purposes. The datasheet specifications are characterized and guaranteed by using a differential signal.

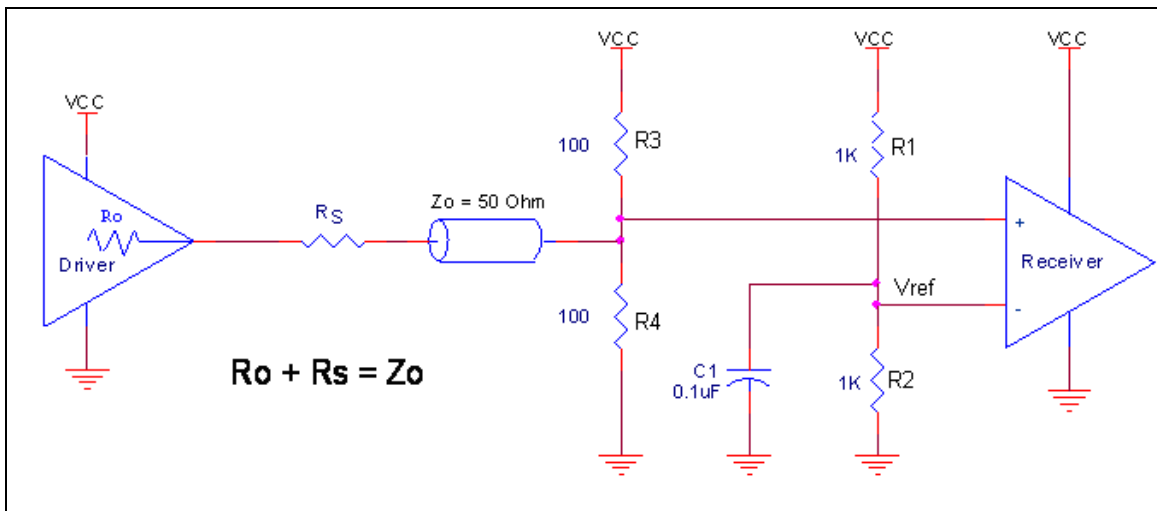
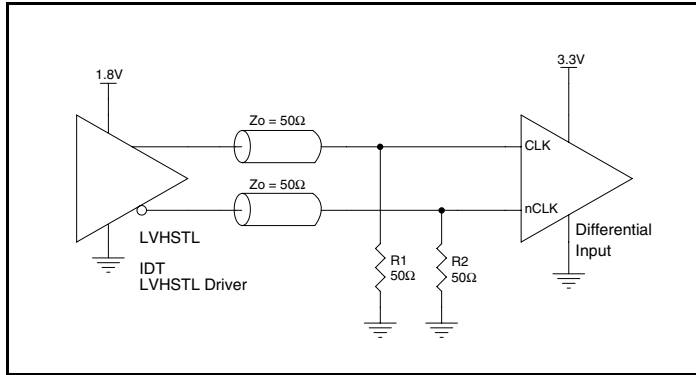


Figure 2. Recommended Schematic for Wiring a Differential Input to Accept Single-ended Levels

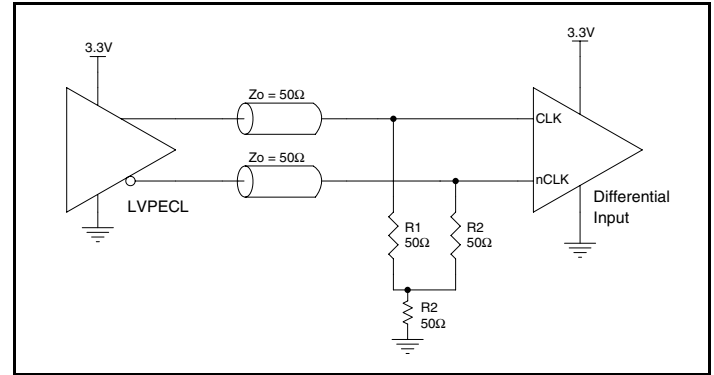
Differential Clock Input Interface

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, SSTL, HCSL and other differential signals. Both signals must meet the V_{PP} and V_{CMR} input requirements. *Figures 3A to 3F* show interface examples for the CLK/nCLK input driven by the most common driver types. The input interfaces suggested here are examples only. Please consult with the

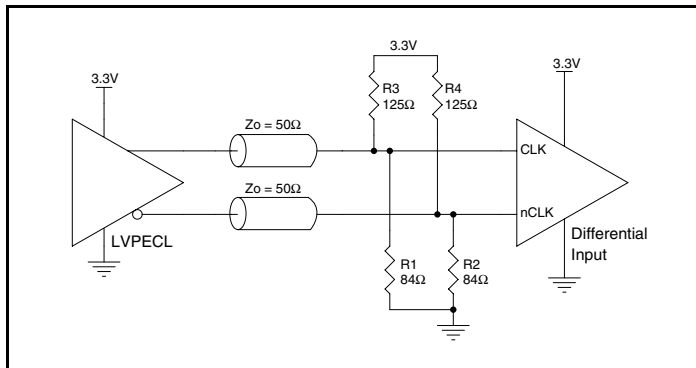
vendor of the driver component to confirm the driver termination requirements. For example, in Figure 3A, the input termination applies for IDT open emitter LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.



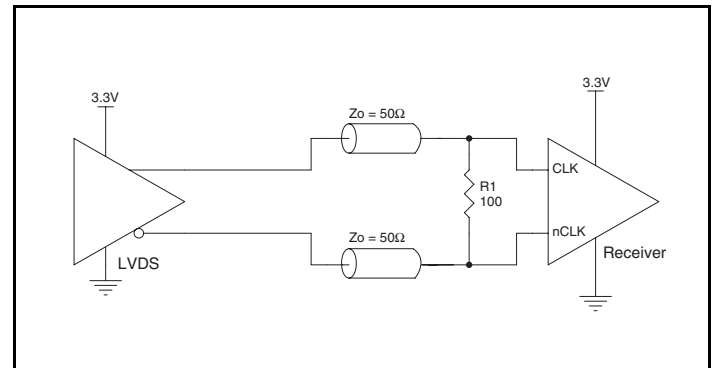
**Figure 3A. CLK/nCLK Input
Driven by an IDT Open Emitter LVHSTL Driver**



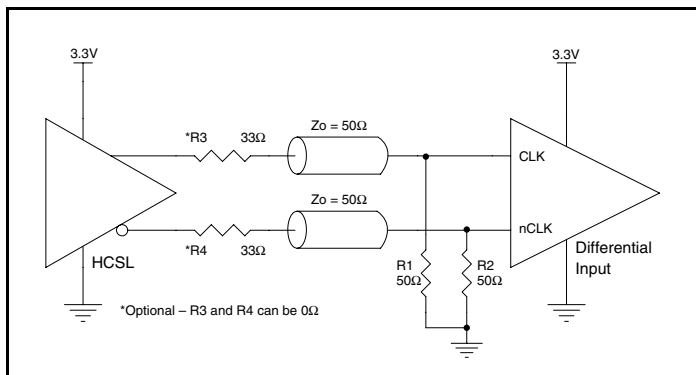
**Figure 3B. CLK/nCLK Input
Driven by a 3.3V LVPECL Driver**



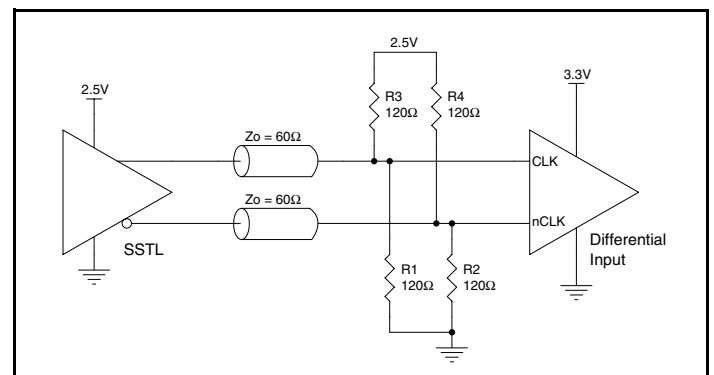
**Figure 3C. CLK/nCLK Input
Driven by a 3.3V LVPECL Driver**



**Figure 3D. CLK/nCLK Input
Driven by a 3.3V LVDS Driver**



**Figure 3E. CLK/nCLK Input
Driven by a 3.3V HCSL Driver**



**Figure 3F. CLK/nCLK Input
Driven by a 2.5V SSTL Driver**

Schematic Example

Figure 4 shows an example of ICS840272I applications schematic. In this example, the device is operated at $V_{DD} = 3.3V$. The input is driven by either a 3.3V LVPECL or LVDS driver. Two examples of LVCMOS

terminations are shown in this schematic. The decoupling capacitors should be located as close as possible to the power pin.

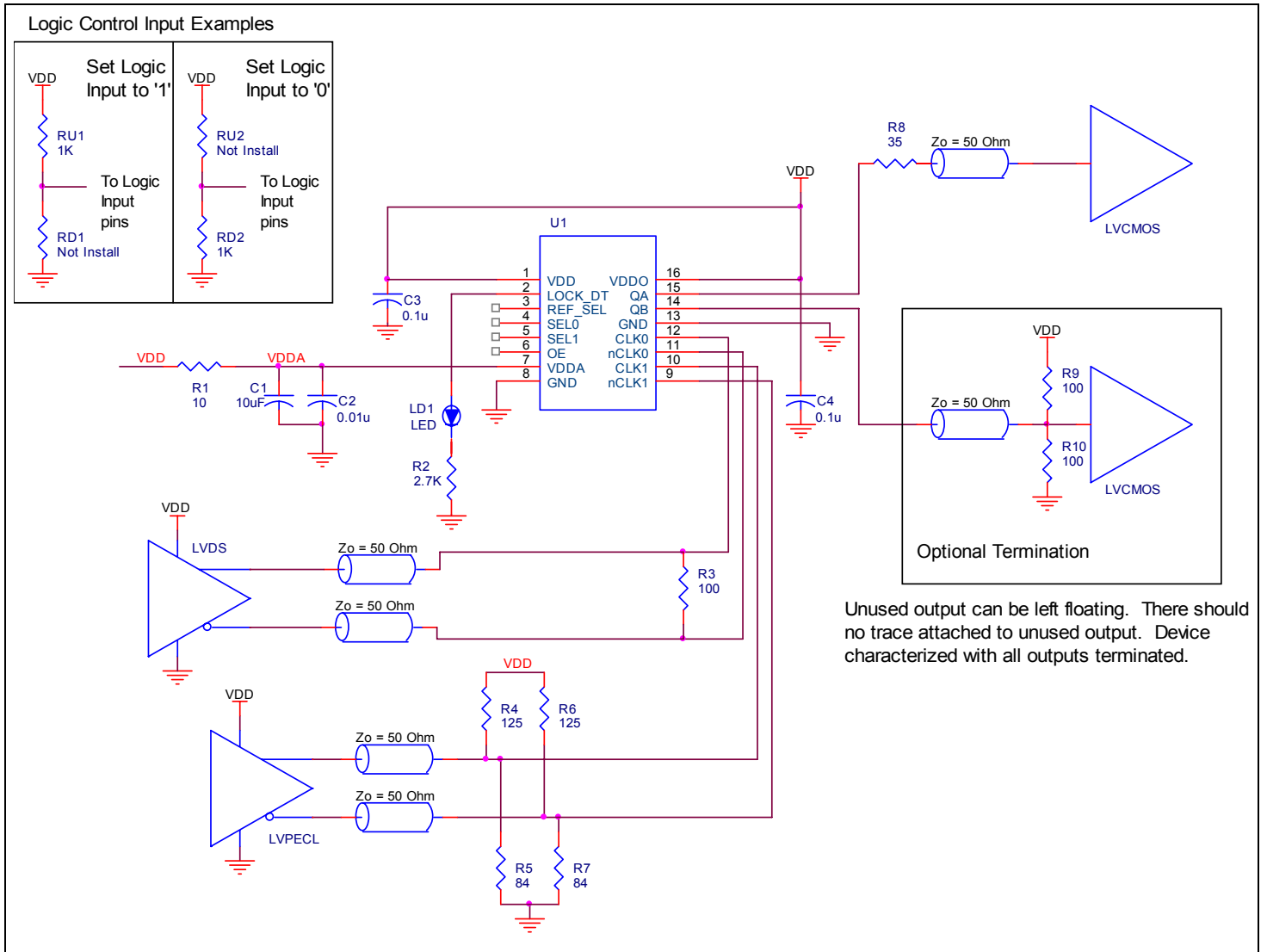


Figure 4. ICS840272I Schematic Example

Power Considerations

This section provides information on power dissipation and junction temperature for the ICS840272I. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the ICS840272I is the sum of the core power plus the analog power plus the power dissipated in the load(s). The following is the power dissipation for $V_{DD} = 3.3V + 5\% = 3.465V$, which gives worst case results.

- Power (core)_{MAX} = $V_{DD_MAX} * (I_{DD} + I_{DDA} + I_{DDO}) = 3.465V * (57mA + 11mA + 5mA) = \mathbf{252.9mW}$
- Output Impedance R_{OUT} Power Dissipation due to Loading 50Ω to $V_{DD}/2$
Output Current $I_{OUT} = V_{DD_MAX} / [2 * (50\Omega + R_{OUT})] = 3.465V / [2 * (50\Omega + 17\Omega)] = \mathbf{25.86mA}$
- Total Power Dissipation on the R_{OUT} per LVCMOS output
Power (R_{OUT}) = $R_{OUT} * (I_{OUT})^2 = 17\Omega * (25.86mA)^2 = \mathbf{11.4mW}$ per output
Total Power (R_{OUT}) = $11.4mW * 2 = 22.8mW$

Total Power Dissipation

- Total Power**
= Power (core)_{MAX} + Total Power (R_{OUT})
= $252.9mW + 22.8mW$
= **275.7mW**

2. Junction Temperature.

Junction temperature, T_j , is the temperature at the junction of the bond wire and bond pad directly affects the reliability of the device. The maximum recommended junction temperature is $125^\circ C$. Limiting the internal transistor junction temperature, T_j , to $125^\circ C$ ensures that the bond wire and bond pad temperature remains below $125^\circ C$.

The equation for T_j is as follows: $T_j = \theta_{JA} * Pd_total + T_A$

T_j = Junction Temperature

θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming no air flow and a multi-layer board, the appropriate value is $81.2^\circ C/W$ per Table 6 below.

Therefore, T_j for an ambient temperature of $85^\circ C$ with all outputs switching is:

$$85^\circ C + 0.276W * 81.2^\circ C/W = 107.4^\circ C. \text{ This is below the limit of } 125^\circ C.$$

This calculation is only an example. T_j will obviously vary depending on the number of loaded outputs, supply voltage, air flow and the type of board (multi-layer).

Table 6. Thermal Resistance θ_{JA} for 16 Lead TSSOP, Forced Convection

θ_{JA} by Velocity			
Meters per Second	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	$81.2^\circ C/W$	$73.9^\circ C/W$	$70.2^\circ C/W$

Reliability Information

Table 7. θ_{JA} vs. Air Flow Table for a 16 Lead TSSOP

θ_{JA} vs. Air Flow			
Meters per Second	0	1	2.5
Multi-Layer PCB, JEDEC Standard Test Boards	81.2°C/W	73.9°C/W	70.2°C/W

Transistor Count

The transistor count for ICS840272I: 3326

Package Outline and Package Dimensions

Package Outline - G Suffix for 16 Lead TSSOP

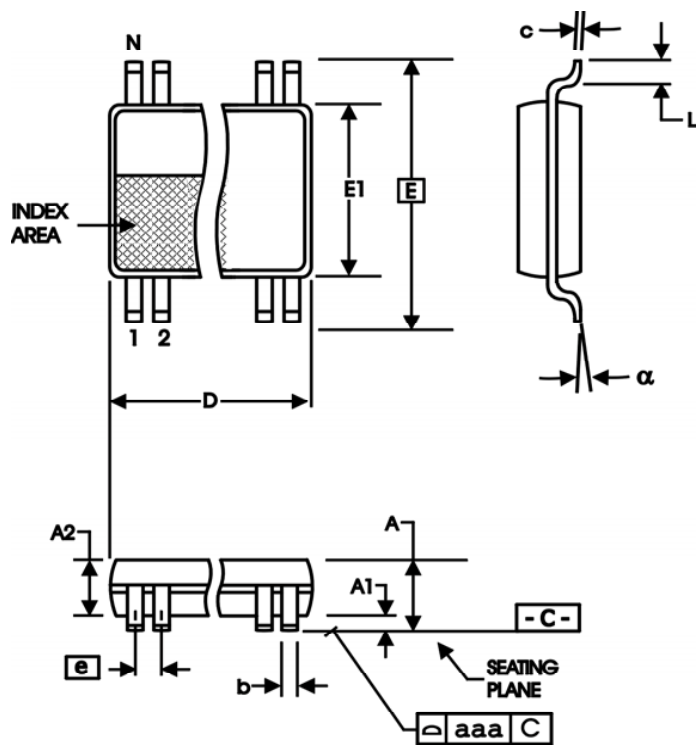


Table 8. Package Dimensions for 16 Lead TSSOP

All Dimensions in Millimeters		
Symbol	Minimum	Maximum
N	16	
A		1.20
A1	0.5	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E	6.40 Basic	
E1	4.30	4.50
e	0.65 Basic	
L	0.45	0.75
α	0°	8°
aaa		0.10

Reference Document: JEDEC Publication 95, MO-153

Ordering Information

Table 9. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
840272AGILF	40272AIL	"Lead-Free" 16 Lead TSSOP	Tube	-40°C to 85°C
840272AGILFT	40272AIL	"Lead-Free" 16 Lead TSSOP	2500 Tape & Reel	-40°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS compliant.

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